

High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

FEATURES AND BENEFITS

- IEC/UL 60950-1 Ed. 2 certified to:
- □ Dielectric Strength = 4800 Vrms (tested for 60 seconds)
 □ Basic Isolation = 1550 Vpeak
- \Box Reinforced Isolation = 800 Vpeak
- Small footprint, low-profile SOIC16 wide-body package suitable for space constrained applications that require high galvanic isolation
- $0.85 \text{m}\Omega$ primary conductor for low power loss and high inrush current withstand capability
- Low, 350 µA_{RMS}/√Hz noise density results in typical input referred noise of 70 mA(rms) at max bandwidth (40 kHz)
- 5.0 V, single supply operation
- · Output voltage proportional to AC or DC current
- Factory-trimmed sensitivity and quiescent output voltage for improved accuracy
- Chopper stabilization results in extremely stable quiescent output voltage
- Ratiometric output from supply voltage





Package: 16-Pin SOICW (suffix MA)



Not to scale

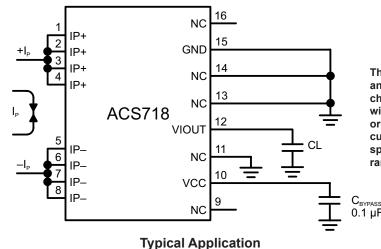
DESCRIPTION

The Allegro[™] ACS718 current sensor IC is an economical, high isolation solution for AC or DC current sensing in industrial, commercial, and communications systems. The small package is ideal for space constrained applications, though the wide-body provides the creepage and clearance needed for high isolation. Typical applications include motor control, load detection and management, switched-mode power supplies, and overcurrent fault protection.

The device consists of a low-offset, linear Hall sensor circuit with a copper conduction path located near the surface of the die. Applied current flowing through this copper conduction path generates a magnetic field which is sensed by the integrated Hall IC and converted into a proportional voltage. Device accuracy is optimized through the close proximity of the magnetic field to the Hall transducer. A proportional voltage is provided by the low-offset, chopper-stabilized BiCMOS Hall IC, which is programmed for accuracy after packaging. The output of the device has a positive slope when an increasing current flows through the primary copper conduction path (from pins 1 through 4, to pins 5 through 8), which is the path used for current sensing. The internal resistance of this conductive path is $0.85 \text{ m}\Omega$ typical, providing low power loss.

The terminals of the conductive path are electrically isolated from the sensor leads (pins 10 through 15). This allows the ACS718 current sensor IC to be used in high-side current sense applications without the use of high-side differential amplifiers or other costly isolation techniques.

The ACS718 is provided in a small, low profile surface mount SOICW16 package (suffix MA). The device is lead (Pb) free with 100% matte tin leadframe plating. The device is fully calibrated prior to shipment from the factory.



The ACS718 outputs an analog signal, V_{IOUT} , that changes, proportionally, with the bidirectional AC or DC primary sensed current, I_p , within the specified measurement range.

$\begin{array}{l} \text{High Isolation Linear Current Sensor IC} \\ \text{with 850 } \mu\Omega \text{ Current Conductor} \end{array}$

SPECIFICATIONS

SELECTION GUIDE

Part Number	I _P (A)	Sens(Typ) at V _{CC} = 5.0 V (mV/A)	T _A (°C)	Packing ^[1]	
ACS718KMATR-10B-T ^[2]	±10	200	40 to 125	Tana and real 1000 pieces per real	
ACS718KMATR-20B-T ^[2]	±20	100	-40 to 125	Tape and reel, 1000 pieces per reel	

^[1] Contact Allegro for additional packing options.

^[2] Varient not intended for automotive applications.

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V _{cc}		7	V
Reverse Supply Voltage	V _{RCC}		-0.1	V
Output Voltage	V _{IOUT}		25	V
Reverse Output Voltage	V _{RIOUT}		-0.1	V
Operating Ambient Temperature	T _A	Range K	-40 to 125	°C
Junction Temperature	T _{J(max)}		165	°C
Storage Temperature	T _{stg}		–65 to 165	°C

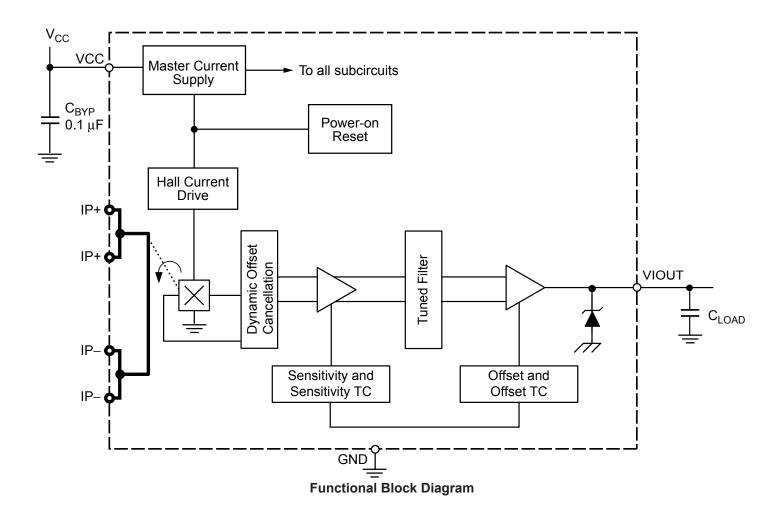
ISOLATION CHARACTERISTICS

Characteristic	Symbol	Notes	Rating	Unit
Dielectric Strength Test Voltage V _{ISC}		Agency type tested for 60 seconds per IEC/UL 60950-1 (2nd Edition). Production tested for 1 second at 3000 $\rm V_{RMS}$ in accordance with IEC/UL 60950-1 (2nd Edition).	4800	V _{RMS}
		Maximum annual marking values for basis (single) isolation	1550	V _{PK}
Working Voltage for Basic Isolation	V _{WVBI}	Maximum approved working voltage for basic (single) isolation according IEC/UL 60950-1 (2nd Edition)	1097	V _{RMS or} VDC
		Maximum approved working voltage for reinforced isolation	800	V _{PK}
Working Voltage for Reinforced Isolation	V _{WVRI}	according to IEC/UL 60950-1 (2nd Edition)	565	V _{RMS or} VDC
Clearance	D _{cl}	Minimum distance through air from IP leads to signal leads.	7.5	mm
Creepage [3] D _{cr} Minimum distance along package body from IP leads to sign leads.		8.2	mm	

^[3] In order to maintain this creepage in applications, the user should add a slit in the PCB under the package. Otherwise, the pads on the PCB will reduce the creepage.



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Pinout Diagram and Terminal List Table

IP+ 1	16 NC
IP+ 2	15 GND
IP+ 3	14 NC
IP+ 4	13 NC
IP-5	12 VIOUT
IP-6	11 NC
IP-7	10 VCC
IP-8	9 NC
	 1

Package MA, 16-Pin SOICW

Terminal List

Number	Name	Description
1, 2, 3, 4	IP+	Terminals for current being sensed; fused internally
5, 6, 7, 8	IP-	Terminals for current being sensed; fused internally
9, 16	NC	No internal connection; recommended to be left unconnected in order to maintain high creepage.
11, 13. 14	NC	No internal connection; recommended to connect to GND for the best ESD performance
10	VCC	Device power supply terminal
12	VIOUT	Analog output signal
15	GND	Signal ground terminal



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$\begin{array}{l} \text{High Isolation Linear Current Sensor IC} \\ \text{with 850 } \mu\Omega \text{ Current Conductor} \end{array}$

COMMON ELECTRICAL CHARACTERISTICS ^[1]: T_A Range K, valid at $T_A = -40$ °C to 125°C, $V_{CC} = 5$ V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Supply Voltage	V _{CC}		4.5	5	5.5	V
Supply Current	I _{CC}	V _{CC} = 5 V, output open	-	7	9	mA
Output Capacitance Load	CL	VIOUT to GND	-	_	1	nF
Output Resistive Load	RL	VIOUT to GND	15	_	_	kΩ
Primary Conductor Resistance	R _P	$T_A = 25^{\circ}C$	-	0.85	_	mΩ
Rise Time	t _r	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = open$	-	10	-	μs
Magnetic Coupling Factor	C _F		-	4.5	-	G/A
Propagation Delay	t _{pd}	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = open$	-	5	-	μs
Response Time	t _{RESPONSE}	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = open$	-	13	-	μs
Internal Bandwidth	BWi	Small signal –3 dB	-	40	-	kHz
Noise Density	I _{ND}	Input referenced noise density; $T_A = 25^{\circ}C$, $C_L = 1 \text{ nF}$	-	350	-	µA _(rms) / √Hz
Noise	I _N	Input referenced noise; BWi = 40 kHz, $T_A = 25^{\circ}C$, $C_L = 1 \text{ nF}$	-	70	-	mA _(rms)
Nonlinearity	E _{LIN}	Across full range of I _P	-	±1	_	%
Saturation Valtage [2]	V _{OH}	$R_L = R_L(min)$	V _{CC} - 0.3	_	_	V
Saturation Voltage ^[2]	V _{OL}	$R_L = R_L(min)$	-	_	0.3	V
Power-On Time	t _{PO}	Output reaches 90% of steady-state level, $T_A = 25^{\circ}C$, $I_P = I_P(max)$	-	35	_	μs

^[1] Device may be operated at higher primary current levels, I_P, ambient temperatures, T_A, and internal leadframe temperatures, provided the Maximum Junction Temperature, T_J(max), is not exceeded.

^[2] The sensor IC will continue to respond to current beyond the range of I_P until the high or low saturation voltage; however, the nonlinearity in this region will be worse than through the rest of the measurement range.



High Isolation Linear Current Sensor IC with 850 $\mu\Omega$ Current Conductor

xKMATR-10B PERFORMANCE CHARACTERISTICS: Valid at $T_A = -40^{\circ}$ C to 125°C, $V_{CC} = 5 V$,

unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE	<u>.</u>			· · · · · · · · · · · · · · · · · · ·		
Current Sensing Range	I _{PR}		-10	-	10	A
Sensitivity	Sens	$I_{PR}(min) < I_P < I_{PR}(max)$	-	200	_	mV/A
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; I _P = 0 A	-	V _{CC} × 0.5	_	V
ACCURACY PERFORMANCE						
		$I_P = I_{PR(max)}; T_A = 25^{\circ}C$	-5	±2	5	%
Total Output Error ^[2]	_	$I_P = I_{PR(max)}; T_A = 85^{\circ}C$	-	±2	_	%
	E _{TOT}	$I_P = I_{PR(max)}; T_A = 125^{\circ}C$	-	±4	_	%
		$I_{P} = I_{PR(max)}; T_{A} = -40^{\circ}C$	-	±4	_	%
TOTAL OUTPUT ERROR COM	IPONENTS	^[3] E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens x I _P)				
	E _{SENS}	$T_A = 25^{\circ}C$; measured at $I_P = I_{PR(max)}$	-4	±2	4	%
Sensitivity Error		$T_A = 85^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	±2	_	%
Sensitivity End		$T_A = 125^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	±3	_	%
		$T_A = -40^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	±4	_	%
		$T_{A} = 25^{\circ}C; I_{P} = 0 A$	-40	±10	40	mV
Offset Voltage [4]	V	T _A = 85°C; I _P = 0 A	-	±15	_	mV
Oliset Voltage	V _{OE}	T _A = 125°C; I _P = 0 A	-	10 ±20	_	mV
		$T_{A} = -40^{\circ}C; I_{P} = 0 A$	-	±25	_	mV
LIFETIME DRIFT CHARACTE	RISTICS					
Sensitivity Error Lifetime Drift	E _{SENS_} DRIFT		-	±2	_	%
Total Output Error Lifetime Drift	E _{TOT_DRIFT}		-	±2	_	%

 $^{[1]}$ Typical values with \pm are 3 sigma values.

 [3] A single part will not have both the maximum/minimum sensitivity error and maximum/minimum offset voltage, as that would violate the maximum/minimum total output error specification. Also, 3 sigma distribution values are combined by taking the square root of the sum of the squares. See Application Information section.

[4] Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.



High Isolation Linear Current Sensor IC with 850 $\mu\Omega$ Current Conductor

xKMATR-20B PERFORMANCE CHARACTERISTICS: Valid at $T_A = -40^{\circ}$ C to 125°C, $V_{CC} = 5 V$,

unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE	<u>.</u>			· · · · · ·		<u>, </u>
Current Sensing Range	I _{PR}		-20	_	20	A
Sensitivity	Sens	$I_{PR}(min) < I_P < I_{PR}(max)$	-	100	_	mV/A
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; I _P = 0 A	-	V _{CC} × 0.5	_	V
ACCURACY PERFORMANCE						
		$I_P = I_{PR(max)}; T_A = 25^{\circ}C$	-5	±2	5	%
Total Output Error ^[2]	_	$I_P = I_{PR(max)}; T_A = 85^{\circ}C$	-	1 ±2	_	%
Total Output Error ^[2]	E _{TOT}	$I_P = I_{PR(max)}; T_A = 125^{\circ}C$	-	2 ±3	_	%
		$I_{P} = I_{PR(max)}; T_{A} = -40^{\circ}C$	-	±3	_	%
TOTAL OUTPUT ERROR COM	IPONENTS	^[3] E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens x I _P)				
	E _{SENS}	$T_A = 25^{\circ}C$; measured at $I_P = I_{PR(max)}$	-4	±2	4	%
Sensitivity Error		$T_A = 85^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	1 ±2	_	%
Sensitivity End		$T_A = 125^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	2 ±3	_	%
		$T_A = -40^{\circ}C$; measured at $I_P = I_{PR(max)}$	-	±3	_	%
		T _A = 25°C; I _P = 0 A;	-40	±8	40	mV
Offect Voltage ^[4]		$T_{A} = 85^{\circ}C; I_{P} = 0 A;$	-	±10	_	mV
Offset Voltage ^[4]	V _{OE}	T _A = 125°C; I _P = 0 A;	_	±15	_	mV
		$T_{A} = -40^{\circ}C; I_{P} = 0 A$	_	±15	_	mV
LIFETIME DRIFT CHARACTE	RISTICS					
Sensitivity Error Lifetime Drift	E _{SENS_} DRIFT		-	±2	_	%
Total Output Error Lifetime Drift	E _{TOT_DRIFT}		-	±2	_	%

 $^{[1]}$ Typical values with \pm are 3 sigma values.

 [3] A single part will not have both the maximum/minimum sensitivity error and maximum/minimum offset voltage, as that would violate the maximum/minimum total output error specification. Also, 3 sigma distribution values are combined by taking the square root of the sum of the squares. See Application Information section.

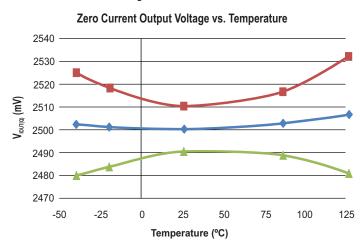
[4] Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.

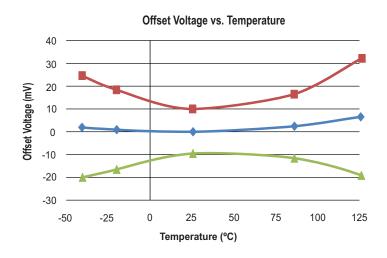


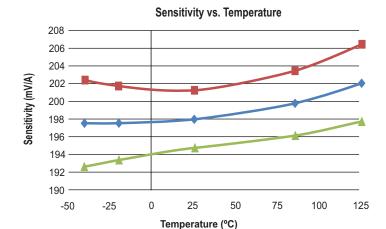
High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

CHARACTERISTIC PERFORMANCE

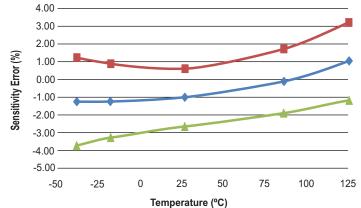
xKMATR-10B Key Parameters

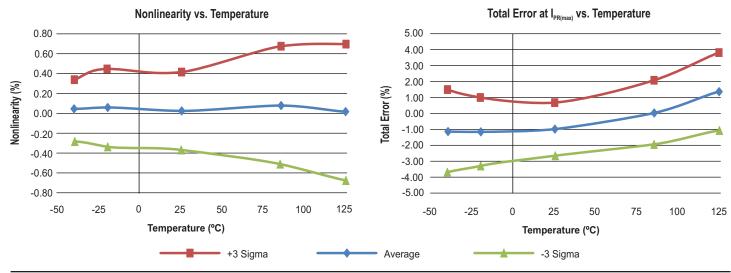






Sensitivity Error vs. Temperature







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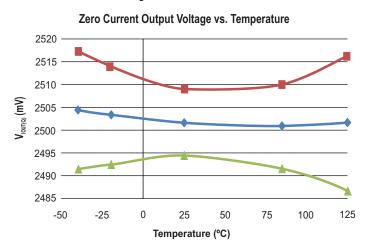
97

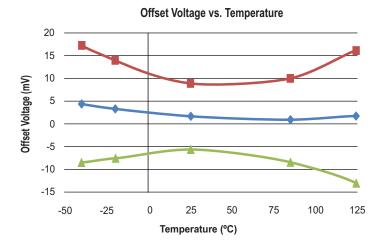
96

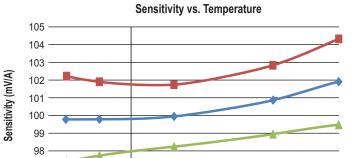
-50

High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

xKMATR-20B Key Parameters







25

Temperature (°C)

50

75

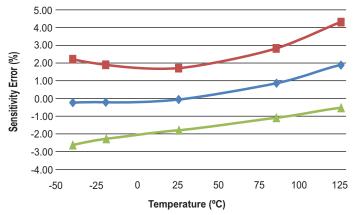
100

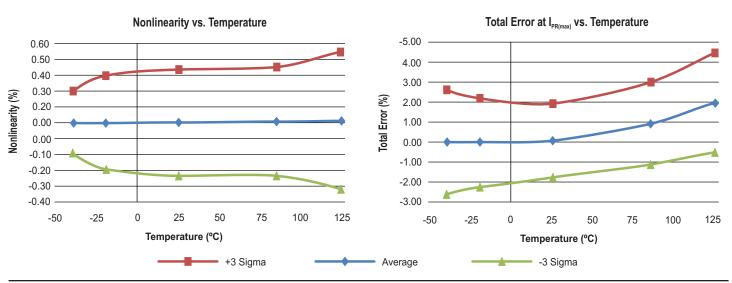
125

0

-25

Sensitivity Error vs. Temperature







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High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

DEFINITIONS OF ACCURACY CHARACTERISTICS

Sensitivity (Sens). The change in sensor IC output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) (1 G = 0.1 mT) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

Nonlinearity (E_{LIN}). The nonlinearity is a measure of how linear the output of the sensor IC is over the full current measurement range. The nonlinearity is calculated as:

$$100 \left\{ 1 - \left[\frac{\Delta \text{ gain} \times \% \text{ sat } (V_{\text{IOUT}} \text{ full-scale amperes } - V_{\text{IOUT}(Q)})}{2 (V_{\text{IOUT}} \text{ half-scale amperes } - V_{\text{IOUT}(Q)})} \right] \right\}$$

where $V_{IOUT}(I_{PR}(max))$ is the output of the sensor IC with the maximum measurement current flowing through it and $V_{IOUT}(I_{PR}(max)/2)$ is the output of the sensor IC with half of the maximum measurement current flowing through it.

Zero Current Output Voltage (V_{IOUT(Q)}). The output of the sensor when the primary current is zero. For a unipolar supply voltage, it nominally remains at at $0.5 \times V_{CC}$ for a bidirectional device and $0.1 \times V_{CC}$ for a unidirectional device. For example, in the case of a bidirectional output device, $V_{CC} = 5$ V translates into $V_{IOUT(Q)} = 2.5$ V. Variation in $V_{IOUT(Q)}$ can be attributed to the resolution of the Allegro linear IC quiescent voltage trim and thermal drift.

Offset Voltage (V_{OE}). The deviation of the device output from its ideal quiescent value of $0.5 \times V_{CC}$ (bidirectional) or $0.1 \times V_{CC}$ (unidirectional) due to nonmagnetic causes. To convert this voltage to amperes, divide by the device sensitivity, Sens.

Total Output Error (E_{TOT}). The the difference between the current measurement from the sensor IC and the actual current (I_p), relative to the actual current. This is equivalent to the difference between the ideal output voltage and the actual output voltage, divided by the ideal sensitivity, relative to the current flowing through the primary conduction path:

$$E_{\text{TOT}}(I_{\text{P}}) = \frac{V_{\text{IOUT_ideal}}(I_{\text{P}}) - V_{\text{IOUT}}(I_{\text{P}})}{\text{Sens}_{\text{ideal}}(I_{\text{P}}) \times I_{\text{P}}} \times 100$$
(%)

The Total Output Error incorporates all sources of error and is a function of I_P. At relatively high currents, E_{TOT} will be mostly due to sensitivity error, and at relatively low currents, E_{TOT} will be mostly due to Offset Voltage (V_{OE}). In fact, at I_P = 0, E_{TOT} approaches infinity due to the offset. This is illustrated in figures 1 and 2. Figure 1 shows a distribution of output voltages versus I_P at 25°C and across temperature. Figure 2 shows the corresponding E_{TOT} versus I_P.

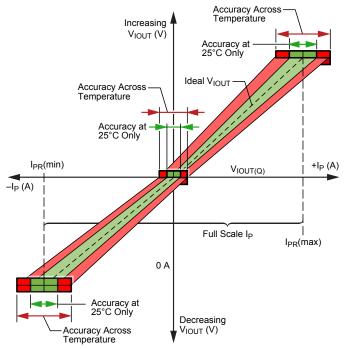


Figure 1: Output Voltage versus Sensed Current

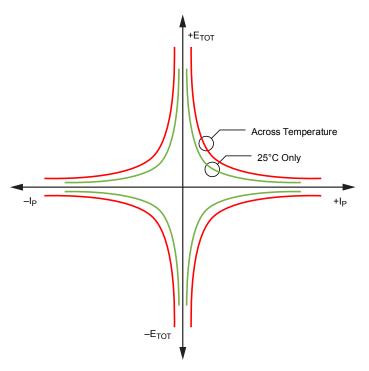


Figure 2: Total Output Error versus Sensed Current



High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

APPLICATION INFORMATION

Impact of External Magnetic Fields

The ACS718 works by sensing the magnetic field created by the current flowing through the package. However, the sensor cannot differentiate between fields created by the current flow and external magnetic fields. This means that external magnetic fields can cause errors in the output of the sensor. Magnetic fields which are perpendicular to the surface of the package affect the output of the sensor, as it only senses fields in that one plane. The error in Amperes can be quantified as:

$$Error(B) = \frac{B}{C_A}$$

where B is the strength of the external field perpendicular to the surface of the package in Gauss, and C_F is the coupling factor in G/A. Then, multiplying by the sensitivity of the part (Sens) gives the error in mV.

For example, an external field of 1 Gauss will result in around 0.22 A of error. If the ACS718KMATR-10B, which has a nominal sensitivity of 200 mV/A, is being used, that equates to 44 mV of error on the output of the sensor.

External Field		Error	(mV)
(Gauss)	Error (A)	10B	20B
0.5	0.11	22	11
1	0.22	44	22
2	0.44	88	44

Estimating Total Error vs. Sensed Current

The Performance Characteristics tables give distribution (± 3 sigma) values for Total Error at $I_{PR(max)}$; however, one often wants to know what error to expect at a particular current. This can be estimated by using the distribution data for the components of Total Error, Sensitivity Error, and Offset Voltage. The

 ± 3 sigma value for Total Error (E_{TOT}) as a function of the sensed current (I_P) is estimated as:

$$E_{TOT}(I_P) = \sqrt{E_{SENS}^2 + \left(\frac{100 \times V_{OE}}{Sens \times I_P}\right)^2}$$

Here, E_{SENS} and V_{OE} are the ± 3 sigma values for those error terms. If there is an average sensitivity error or average offset voltage, then the average Total Error is estimated as:

$$E_{TOT_{AVG}}(I_p) = E_{SENS_{AVG}} + \frac{100 \times V_{OE_{AVG}}}{Sens \times I_p}$$

The resulting total error will be a sum of E_{TOT} and E_{TOT_AVG} . Using these equations and the 3 sigma distributions for Sensitivity Error and Offset Voltage, the Total Error vs. sensed current (I_p) is below for the ACS718KMATR-20B. As expected, as one goes towards zero current, the error in percent goes towards infinity due to division by zero (refer to Figure 3).

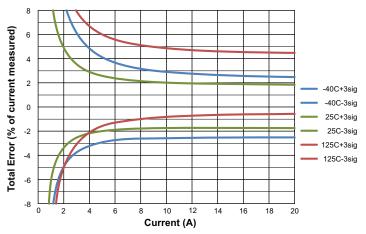


Figure 3: Predicted Total Error as a Function of Sensed Current for the ACS718KMATR-20B



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DEFINITIONS OF DYNAMIC RESPONSE CHARACTERISTICS

Power-On Time (t_{PO})

When the supply is ramped to its operating voltage, the device requires a finite time to power its internal components before responding to an input magnetic field.

Power-On Time, t_{PO} , is defined as the time it takes for the output voltage to settle within ±10% of its steady state value under an applied magnetic field, after the power supply has reached its minimum specified operating voltage, $V_{CC}(min)$, as shown in the chart at right.

Rise Time (t_r)

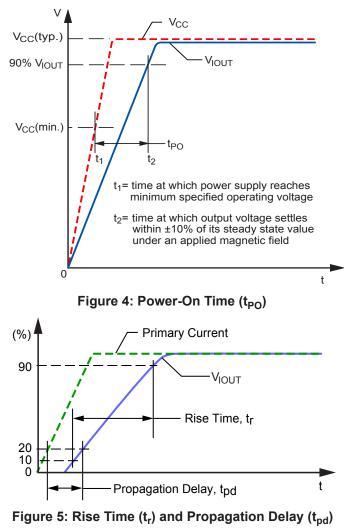
The time interval between a) when the sensor IC reaches 10% of its full scale value, and b) when it reaches 90% of its full scale value.

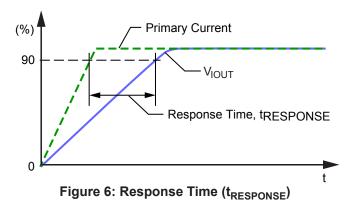
Propagation Delay (t_{pd})

The propagation delay is measured as the time interval a) when the primary current signal reaches 20% of its final value, and b) when the device reaches 20% of its output corresponding to the applied current.

Response Time (t_{RESPONSE})

The time interval between a) when the primary current signal reaches 90% of its final value, and b) when the device reaches 90% of its output corresponding to the applied current.

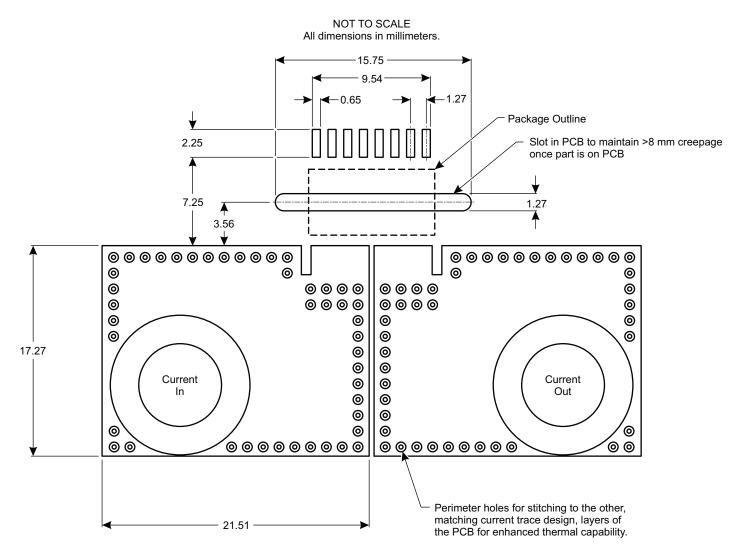






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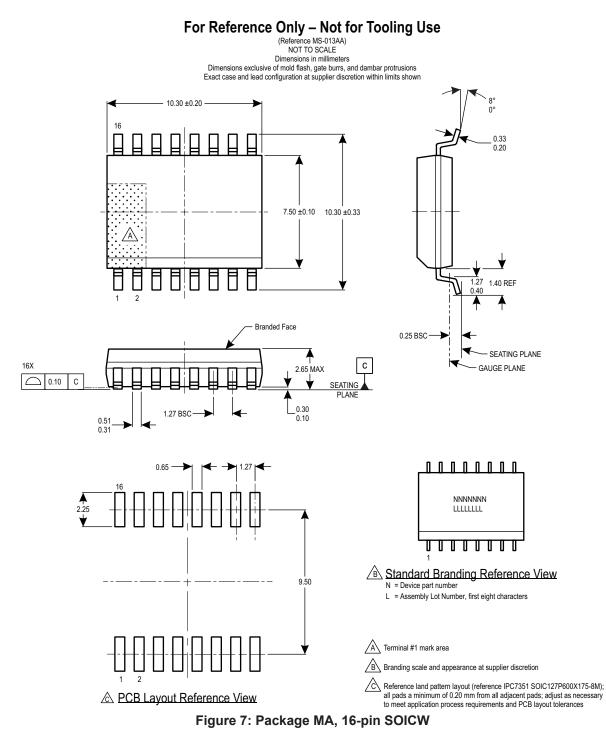
HIGH ISOLATION PCB LAYOUT





High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

PACKAGE OUTLINE DRAWING





High Isolation Linear Current Sensor IC with 850 μΩ Current Conductor

Revision History

Number	Date	Description
-	December 15, 2014	Initial Release
1	June 15, 2015	Corrected pinout diagram
2	April 13, 2016	Corrected Package Outline Drawing branding information (page 13).
3	December 14, 2018	Updated certificate numbers and minor editorial updates
4	May 21, 2019	Updated TUV certificate mark

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